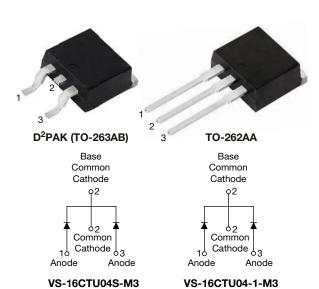


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# Ultrafast Rectifier, 16 A FRED Pt®



| PRIMARY CHARACTERISTICS          |   |  |  |  |  |
|----------------------------------|---|--|--|--|--|
| I <sub>F(AV)</sub>               | 2 x 8 A                                 |  |  |  |  |
| V <sub>R</sub>                   | 400 V                                   |  |  |  |  |
| V <sub>F</sub> at I <sub>F</sub> | 0.94 V                                  |  |  |  |  |
| t <sub>rr</sub> typ.             | 35 ns                                   |  |  |  |  |
| T <sub>J</sub> max.              | 175 °C                                  |  |  |  |  |
| Package                          | D <sup>2</sup> PAK (TO-263AB), TO-262AA |  |  |  |  |
| Circuit configuration            | Common cathode                          |  |  |  |  |

#### **FEATURES**

- Ultrafast recovery time
- Low forward voltage drop
- · Low leakage current
- 175 °C operating junction temperature
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Material categorization: for definitions of compliance please see <a href="https://www.vishav.com/doc?99912"><u>www.vishav.com/doc?99912</u></a>

### ROHS COMPLIANT HALOGEN FREE

### **DESCRIPTION / APPLICATIONS**

Vishay Semiconductors FRED Pt® series are the state of the art ultrafast recovery rectifiers specifically designed with optimized performance of forward voltage drop and ultrafast recovery time.

The planar structure and the platinum doped life time control, guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, UPS, DC/DC converters as well as freewheeling diode in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

| ABSOLUTE MAXIMUM RATINGS                       |                                   |   |             |       |  |  |  |  |
|--|-----------------------------------|---|-------------|-------|--|--|--|--|
| PARAMETER                                      | SYMBOL                            | TEST CONDITIONS   | VALUES      | UNITS |  |  |  |  |
| Peak repetitive reverse voltage                | $V_{RRM}$                         |   | 400         | V     |  |  |  |  |
| Average restified forward surrent              | 1                                 |   | 8           |       |  |  |  |  |
| Average rectified forward current total device | I <sub>F(AV)</sub>                | Rated V <sub>R</sub> , T <sub>C</sub> = 155 °C                      | 16          | ۸     |  |  |  |  |
| Non-repetitive peak surge current              | I <sub>FSM</sub>                  | T <sub>C</sub> = 25 °C  | 100         | Α     |  |  |  |  |
| Peak repetitive forward current                | I <sub>FRM</sub>                  | Rated V <sub>R</sub> , square wave, 20 kHz, T <sub>C</sub> = 155 °C | 16          |       |  |  |  |  |
| Operating junction and storage temperatures    | T <sub>J</sub> , T <sub>Stg</sub> |   | -65 to +175 | °C    |  |  |  |  |

| <b>ELECTRICAL SPECIFICATIONS PER LEG</b> (T <sub>J</sub> = 25 °C unless otherwise specified) |                                     |   |      |      |      |       |  |  |
|--|-------------------------------------|---|------|------|------|-------|--|--|
| PARAMETER  | SYMBOL                              | TEST CONDITIONS   | MIN. | TYP. | MAX. | UNITS |  |  |
| Breakdown voltage,<br>blocking voltage   | V <sub>BR</sub> ,<br>V <sub>R</sub> | I <sub>R</sub> = 100 μA                                 | 400  | -    | -    | ,,    |  |  |
| Forward voltage  | V <sub>F</sub>                      | I <sub>F</sub> = 8 A                                    |      | 1.19 | 1.3  | V     |  |  |
| Forward voltage  | VF                                  | I <sub>F</sub> = 8 A, T <sub>J</sub> = 150 °C           | -    | 0.94 | 1.0  |       |  |  |
| Devenue le alcare e comment  |                                     | $V_R = V_R$ rated                                       | -    | 0.2  | 10   |       |  |  |
| Reverse leakage current I <sub>R</sub>   |                                     | $T_J = 150  ^{\circ}\text{C},  V_R = V_R  \text{rated}$ | -    | 20   | 500  | μA    |  |  |
| Junction capacitance   | C <sub>T</sub>                      | V <sub>R</sub> = 400 V                                  | -    | 14   | -    | pF    |  |  |
| Series inductance  | L <sub>S</sub>                      | Measured lead to lead 5 mm from package body            | -    | 8.0  | -    | nH    |  |  |



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| <b>DYNAMIC RECOVERY CHARACTERISTICS PER LEG</b> (T <sub>J</sub> = 25 °C unless otherwise specified) |                  |                                   |   |      |      |      |       |  |
|---|------------------|-----------------------------------|---|------|------|------|-------|--|
| PARAMETER   | SYMBOL           | TEST CO                           | NDITIONS  | MIN. | TYP. | MAX. | UNITS |  |
|   |                  | $I_F = 1.0 \text{ A, } dI_F/dt =$ | I <sub>F</sub> = 1.0 A, dI <sub>F</sub> /dt = 50 A/μA, V <sub>R</sub> = 30 V          |      |      | 60   |       |  |
| Reverse recovery time   | t <sub>rr</sub>  | T <sub>J</sub> = 25 °C            |   | -    | 43   | -    | ns    |  |
|   |                  | T <sub>J</sub> = 125 °C           |   | -    | 67   | -    |       |  |
| Peak recovery current   |                  | T <sub>J</sub> = 25 °C            | $I_F = 8 \text{ A}$<br>$dI_F/dt = 200 \text{ A/}\mu\text{s}$<br>$V_R = 200 \text{ V}$ | -    | 2.8  | -    | А     |  |
|   | I <sub>RRM</sub> | T <sub>J</sub> = 125 °C           |   | -    | 6.3  | -    |       |  |
| Reverse recovery charge   |                  | T <sub>J</sub> = 25 °C            |   | -    | 60   | -    | 200   |  |
|   | $Q_{rr}$         | T <sub>J</sub> = 125 °C           |   | -    | 210  | -    | nC    |  |

| THERMAL - MECHANICAL SPECIFICATIONS                               |                                   |  |              |      |            |                        |  |  |
|---|-----------------------------------|--|--------------|------|------------|------------------------|--|--|
| PARAMETER   | SYMBOL                            | TEST CONDITIONS                              | MIN.         | TYP. | MAX.       | UNITS                  |  |  |
| Maximum junction and storage temperature range                    | T <sub>J</sub> , T <sub>Stg</sub> |  | -65          | -    | 175        | °C                     |  |  |
| Thermal resistance, junction to case per leg                      | R <sub>thJC</sub>                 |  | -            | 1.8  | 2.0        |                        |  |  |
| Thermal resistance, junction to ambient per leg R <sub>thJA</sub> |                                   | Typical socket mount                         | -            | -    | 50         | °C/W                   |  |  |
| Thermal resistance, case to heatsink                              | R <sub>thCS</sub>                 | Mounting surface, flat, smooth and greased   | -            | 0.5  | -          |                        |  |  |
| Woight  |                                   |  | -            | 2.0  | -          | g                      |  |  |
| Weight  |                                   |  | -            | 0.07 | -          | oz.                    |  |  |
| Mounting torque   |                                   |  | 6.0<br>(5.0) | -    | 12<br>(10) | kgf · cm<br>(lbf · in) |  |  |
| Marking dayioo  |                                   | Case style D <sup>2</sup> PAK (TO-263AB) 160 |              | 16CT | U04S       |                        |  |  |
| Marking device  |                                   | Case style TO-262AA                          |              | 16CT | U04-1      | •                      |  |  |

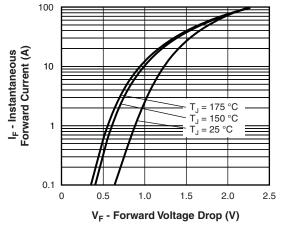


Fig. 1 - Typical Forward Voltage Drop Characteristics

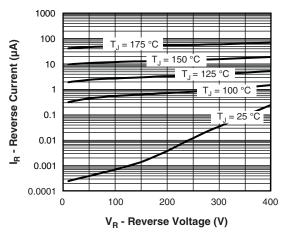


Fig. 2 - Typical Values of Reverse Current vs.Reverse Voltage

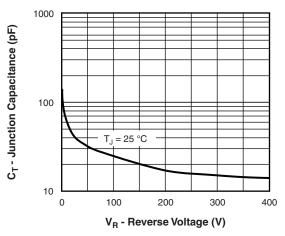


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

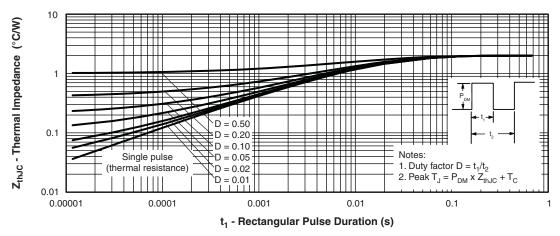


Fig. 4 - Maximum Thermal Impedance  $Z_{\text{thJC}}$  Characteristics

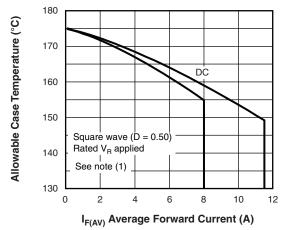


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

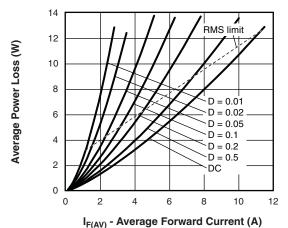


Fig. 6 - Forward Power Loss Characteristics

#### Note

 $\begin{array}{ll} \text{(1)} \ \ \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = \text{forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6)}; \\ Pd_{REV} = \text{inverse power loss} = V_{R1} \times I_R \text{ (1 - D); } I_R \text{ at } V_{R1} = \text{rated } V_R \\ \end{array}$ 

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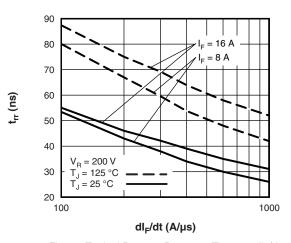


Fig. 7 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

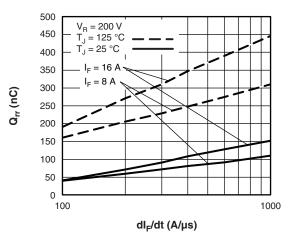
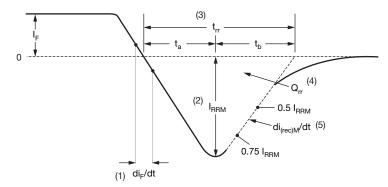


Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt



- (1) di<sub>F</sub>/dt rate of change of current through zero crossing
- (2) I<sub>RRM</sub> peak reverse recovery current
- (3)  $\rm t_{rr}$  reverse recovery time measured from zero crossing point of negative going  $\rm I_F$  to point where a line passing through 0.75  $\rm I_{RRM}$  and 0.50  $\rm I_{RRM}$  extrapolated to zero current.
- (4)  $\mathbf{Q}_{\rm rr}$  area under curve defined by  $\mathbf{t}_{\rm rr}$  and  $\mathbf{I}_{\rm RRM}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) di<sub>(rec)M</sub>/dt - peak rate of change of current during t<sub>b</sub> portion of t<sub>rr</sub>

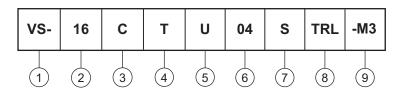
Fig. 9 - Reverse Recovery Waveform and Definitions

## VS-16CTU04S-M3, VS-16CTU04-1-M3

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### **ORDERING INFORMATION TABLE**

**Device code** 



1 - Vishay Semiconductors product

2 - Current rating (16 A)

3 - C = common cathode

- T = TO-220, D<sup>2</sup>PAK (TO-263AB)

5 - U = ultrafast recovery

Voltage rating (04 = 400 V)

7 - • S =  $D^2PAK$  (TO-263AB)

• -1 = TO-262AA

None = tube (50 pieces)

• TRL = tape and reel (left oriented, for D<sup>2</sup>PAK (TO-263AB) package)

• TRR = tape and reel (right oriented, for D<sup>2</sup>PAK (TO-263AB) package)

9 - Environmental digit:

-M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

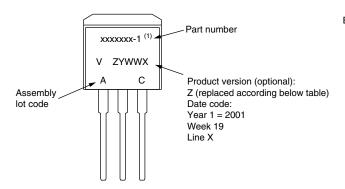
| LINKS TO RELATED DOCUMENTS |                               |                          |  |  |  |
|----------------------------|-------------------------------|--------------------------|--|--|--|
| Dimensions                 | D <sup>2</sup> PAK (TO-263AB) | www.vishay.com/doc?96164 |  |  |  |
| Differsions                | TO-262AA                      | www.vishay.com/doc?96165 |  |  |  |
| Part marking information   | D <sup>2</sup> PAK (TO-263AB) | www.vishay.com/doc?95444 |  |  |  |
| Part marking information   | TO-262AA                      | www.vishay.com/doc?95443 |  |  |  |
| SPICE model                |                               | www.vishay.com/doc?96565 |  |  |  |



## **Part Marking Information**

## Vishay Semiconductors

## **TO-262**



Example: This is a xxxxxxx-1 <sup>(1)</sup> with assembly lot code AC, assembled on WW 19, 2001

in the assembly line "X"

#### Note

(1) If part number contain "H" as last digit, product is AEC-Q101 qualified

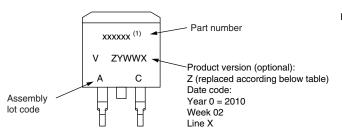
| ENVIRONMENTAL NAMING CODE (Z) | PRODUCT DEFINITION  |  |  |  |
|-------------------------------|---|--|--|--|
| A                             | Termination lead (Pb)-free                                  |  |  |  |
| В                             | Totally lead (Pb)-free                                      |  |  |  |
| E                             | RoHS-compliant and termination lead (Pb)-free               |  |  |  |
| F                             | RoHS-compliant and totally lead (Pb)-free                   |  |  |  |
| М                             | Halogen-free, RoHS-compliant and termination lead (Pb)-free |  |  |  |
| N                             | Halogen-free, RoHS-compliant and totally lead (Pb)-free     |  |  |  |
| G                             | Green   |  |  |  |



# **Part Marking Information**

Vishay Semiconductors

## D<sup>2</sup>PAK



Example: This is a xxxxxx <sup>(1)</sup> with assembly lot code AC, assembled on WW 02, 2010

#### Note

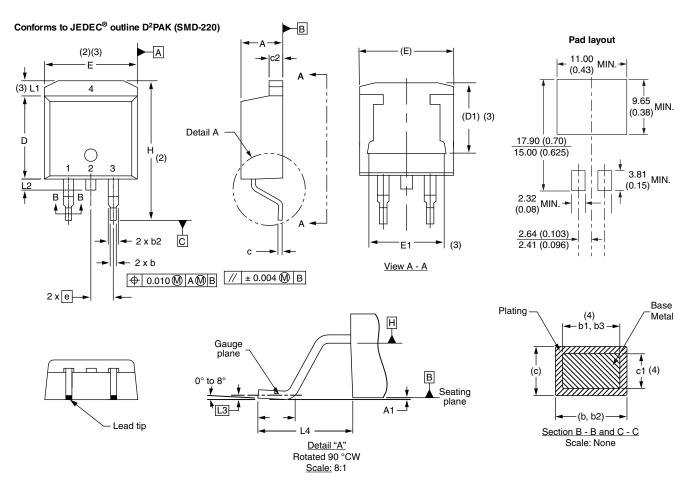
(1) If part number contain "H" as last digit, product is AEC-Q101 qualified

| ENVIRONMENTAL NAMING CODE (Z) | PRODUCT DEFINITION   |  |  |  |
|-------------------------------|--|--|--|--|
| A Termination lead (Pb)-free  |  |  |  |  |
| B Totally lead (Pb)-free      |  |  |  |  |
| E                             | RoHS-compliant and termination lead (Pb)-free                |  |  |  |
| F                             | RoHS-compliant and totally lead (Pb)-free                    |  |  |  |
| M                             | Halogen-free, RoHS-compliant, and termination lead (Pb)-free |  |  |  |
| N                             | Halogen-free, RoHS-compliant, and totally lead (Pb)-free     |  |  |  |
| G                             | Green  |  |  |  |



## D<sup>2</sup>PAK

### **DIMENSIONS** in millimeters and inches



| SYMBOL  | MILLIM | ETERS | INC   | HES   | NOTES | NOTES | SYMBOL  | MILLIM | ETERS | INC   | HES   | NOTES |
|---------|--------|-------|-------|-------|-------|-------|---------|--------|-------|-------|-------|-------|
| STWIBOL | MIN.   | MAX.  | MIN.  | MAX.  | NOTES |       | STWIDOL | MIN.   | MAX.  | MIN.  | MAX.  | NOTES |
| Α       | 4.06   | 4.83  | 0.160 | 0.190 |       |       | D1      | 6.86   | 8.00  | 0.270 | 0.315 | 3     |
| A1      | 0.00   | 0.254 | 0.000 | 0.010 |       |       | E       | 9.65   | 10.67 | 0.380 | 0.420 | 2, 3  |
| b       | 0.51   | 0.99  | 0.020 | 0.039 |       |       | E1      | 7.90   | 8.80  | 0.311 | 0.346 | 3     |
| b1      | 0.51   | 0.89  | 0.020 | 0.035 | 4     |       | е       | 2.54   | BSC   | 0.100 | BSC   |       |
| b2      | 1.14   | 1.78  | 0.045 | 0.070 |       |       | Н       | 14.61  | 15.88 | 0.575 | 0.625 |       |
| b3      | 1.14   | 1.73  | 0.045 | 0.068 | 4     |       | L       | 1.78   | 2.79  | 0.070 | 0.110 |       |
| С       | 0.38   | 0.74  | 0.015 | 0.029 |       |       | L1      | -      | 1.65  | -     | 0.066 | 3     |
| c1      | 0.38   | 0.58  | 0.015 | 0.023 | 4     |       | L2      | 1.27   | 1.78  | 0.050 | 0.070 |       |
| c2      | 1.14   | 1.65  | 0.045 | 0.065 |       |       | L3      | 0.25   | BSC   | 0.010 | BSC   |       |
| D       | 8.51   | 9.65  | 0.335 | 0.380 | 2     |       | L4      | 4.78   | 5.28  | 0.188 | 0.208 |       |

#### Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inches
- (7) Outline conforms to JEDEC® outline TO-263AB

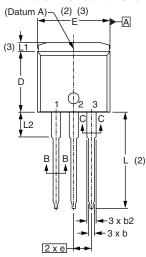
Revision: 13-Jul-17 Document Number: 96164

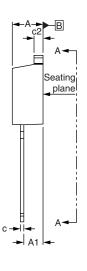


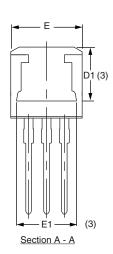
## **TO-262AA**

### **DIMENSIONS** in millimeters and inches

#### Modified JEDEC® outline TO-262







**⊕** 0.010 **M** A**M** B

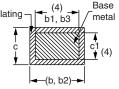
#### Lead assignments



**Diodes** 1. - Anode (two die)/open (one die)

2., 4. - Cathode

3. - Anode



Section B - B and C - C Scale: None

|        |        |        | T     |       |       |
|--------|--------|--------|-------|-------|-------|
| SYMBOL | MILLIN | IETERS | INC   | HES   | NOTES |
| 01D02  | MIN.   | MAX.   | MIN.  | MAX.  | NOTES |
| Α      | 4.06   | 4.83   | 0.160 | 0.190 |       |
| A1     | 2.03   | 3.02   | 0.080 | 0.119 |       |
| b      | 0.51   | 0.99   | 0.020 | 0.039 |       |
| b1     | 0.51   | 0.89   | 0.020 | 0.035 | 4     |
| b2     | 1.14   | 1.78   | 0.045 | 0.070 |       |
| b3     | 1.14   | 1.73   | 0.045 | 0.068 | 4     |
| С      | 0.38   | 0.74   | 0.015 | 0.029 |       |
| c1     | 0.38   | 0.58   | 0.015 | 0.023 | 4     |
| c2     | 1.14   | 1.65   | 0.045 | 0.065 |       |
| D      | 8.51   | 9.65   | 0.335 | 0.380 | 2     |
| D1     | 6.86   | 8.00   | 0.270 | 0.315 | 3     |
| Е      | 9.65   | 10.67  | 0.380 | 0.420 | 2, 3  |
| E1     | 7.90   | 8.80   | 0.311 | 0.346 | 3     |
| е      | 2.54   | BSC    | 0.100 | BSC   |       |
| L      | 13.46  | 14.10  | 0.530 | 0.555 |       |
| L1     | =      | 1.65   | -     | 0.065 | 3     |
| L2     | 3.56   | 3.71   | 0.140 | 0.146 |       |

#### **Notes**

(4) Dimension b1 and c1 apply to base metal only

Controlling dimension: inches

<sup>(1)</sup> Dimensioning and tolerancing as per ASME Y14.5M-1994
(2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

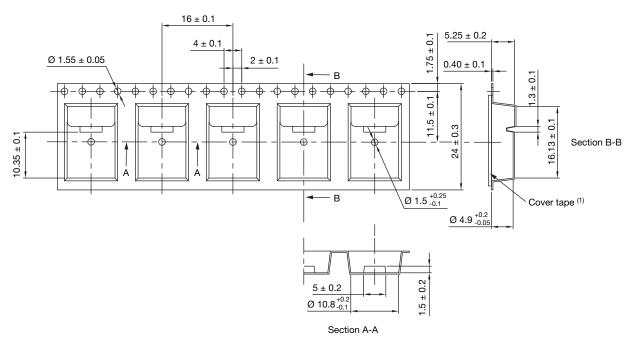
Thermal pad contour optional within dimension E, L1, D1 and E1

Outline conform to JEDEC® TO-262 except A1 (max.), b (min., max.), b1 (min.), b2 (max.), c (min.), c1(min.), c2 (max.), D (min.), E (max.), L1 (max.), L2 (min., max.)



# D<sup>2</sup>PAK (TO-263AB)

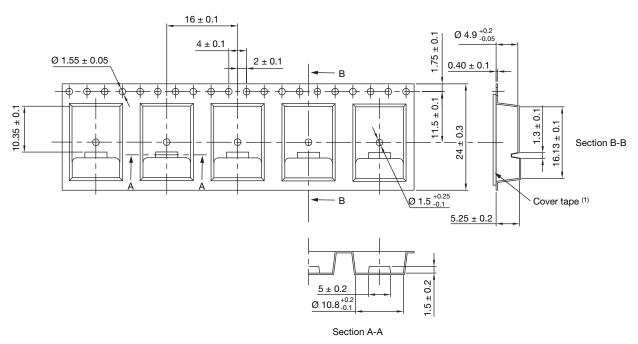
### **CARRIER TAPE FOR TAPE AND REEL LEFT** in millimeters



#### Note

(1) For dimensions, see next pages

### **CARRIER TAPE FOR TAPE AND REEL RIGHT** in millimeters

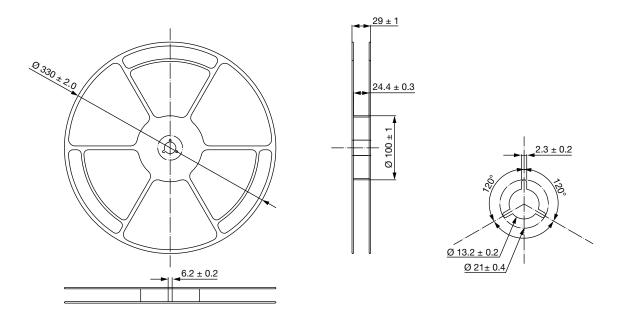


### Note

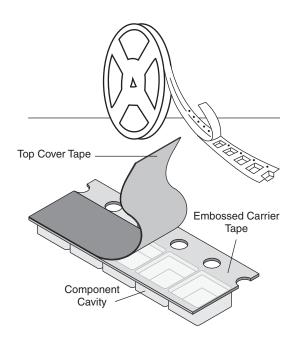
(1) For dimensions, see next pages



### **REEL FOR CARRIER TAPE** in millimeters



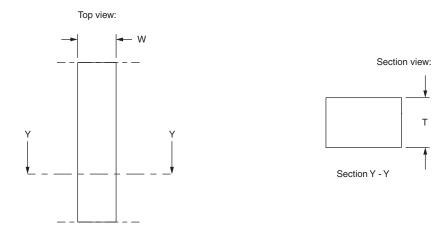
### CARRIER TAPE AND REEL PACKAGING D<sup>2</sup>PAK (TO-263AB)



# **Packaging Information**

Vishay Semiconductors

### **COVER TAPE FOR CARRIER TAPE** in millimeters



| APPLICATION                      | COVER TAPE WIDTH<br>W | COVER TAPE THICKNESS<br>T | CARRIER TAPE WIDTH | MATERIAL                                 |
|----------------------------------|-----------------------|---------------------------|--------------------|--|
| D <sup>2</sup> PAK<br>(TO-263AB) | 21.3 ± 0.1            | 0.060 ± 0.01              | 24                 | Antistatic/treated/transparent/polyester |



## **Legal Disclaimer Notice**

Vishay

### **Disclaimer**

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